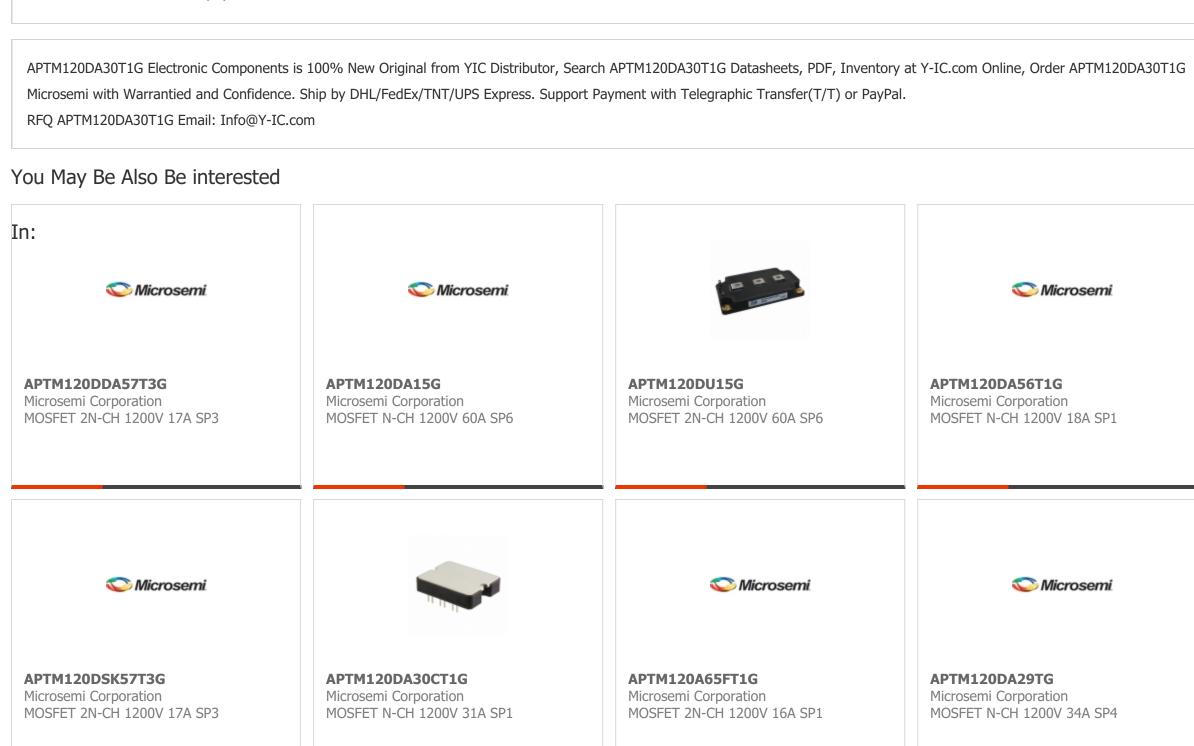


<b>APTM120DA30T1</b>	G
Manufacturer Part Number:	APTM120DA30T1G
Manufacturer/Brand:	Microsemi
Part of Description:	MOSFET N-CH 1200V 31A SP1
Datasheets:	1.APTM120DA30T1G.pdf 2.APTM120DA30T1G.pdf
RoHs Status:	Rohs Lead free / RoHS
Stock Condition:	Compliant New original, Stock Available.
Ship From:	Hong Kong
Shipment Way:	DHL/Fedex/TNT/UPS/EMS

Specifications	
Part Number	APTM120DA30T1G
Manufacturer	Microsemi
Description	MOSFET N-CH 1200V 31A SP1
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	Require For Quote & Check Stock
Vgs(th) (Max) @ Id	5V @ 2.5mA
Technology	MOSFET (Metal Oxide)
Supplier Device Package	SP1
Series	-
Rds On (Max) @ Id, Vgs	360 mOhm @ 25A, 10V
Power Dissipation (Max)	657W (Tc)
Packaging	Bulk
Package / Case	SP1
Operating Temperature	-40°C ~ 150°C (TJ)
Mounting Type	Chassis Mount
Input Capacitance (Ciss) (Max) @ Vds	14560pF @ 25V
Gate Charge (Qg) (Max) @ Vgs	560nC @ 10V
FET Type	N-Channel
FET Feature	-
Drain to Source Voltage (Vdss)	1200V (1.2kV)
Current - Continuous Drain (Id) @ 25°C	31A



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